NSN 5961-00-790-7889

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-790-7889 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 6.0 breakdown voltage, collector-to-emitter, base open all transistor **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: